

5423, 5427*Microcircuits, Digital, TTL, Multiple NOR Gates, Monolithic Silicon***Rochester Electronics
Manufactured Components**

Rochester branded components are manufactured using either die/wafers purchased from the original suppliers or Rochester wafers recreated from the original IP. All re-creations are done with the approval of the Original Component Manufacturer (OCM).

Parts are tested using original factory test programs or Rochester developed test solutions to guarantee product meets or exceeds the OCM data sheet.

Quality Overview

- ISO-9001
- AS9120 certification
- Qualified Manufacturers List (QML) MIL-PRF-35835
 - Class Q Military
 - Class V Space Level
- Qualified Suppliers List of Distributors (QSLD)
 - Rochester is a critical supplier to DLA and meets all industry and DLA standards.

Rochester Electronics, LLC is committed to supplying products that satisfy customer expectations for quality and are equal to those originally supplied by industry manufacturers.

The original manufacturer's datasheet accompanying this document reflects the performance and specifications of the Rochester manufactured version of this device. Rochester Electronics guarantees the performance of its semiconductor products to the original OCM specifications. 'Typical' values are for reference purposes only. Certain minimum or maximum ratings may be based on product characterization, design, simulation, or sample testing.

FOR REFERENCE ONLY

MIL-M-38510/4D
14 December 2004
SUPERSEDING
MIL-M-38510/4C
25 February 1977
MIL-M-0038510/4B(USAF)
15 October 1973

MILITARY SPECIFICATION

MICROCIRCUITS, DIGITAL, TTL, MULTIPLE NOR GATES, MONOLITHIC SILICON

Inactive for new design after 7 September 1995.

This specification is approved for use by all Departments and Agencies of the Department of Defense.

The requirements for acquiring the product herein shall consist of this specification sheet and MIL-PRF 38535

1. SCOPE

1.1 Scope. This specification covers the detail requirements for monolithic, silicon, TTL, positive NOR logic gating microcircuits. Two product assurance classes and a choice of case outlines and lead finishes are provided for each type and are reflected in the complete part number. For this product, the requirements of MIL-M-38510 have been superseded by MIL-PRF-38535, (see 6.3).

1.2 Part or Identifying Number (PIN). The PIN is in accordance with MIL-PRF-38535, and as specified herein.

1.2.1 Device types. The device types are as follows:

<u>Device type</u>	<u>Circuit</u>
01	Quadruple 2-input positive NOR gate
02	Dual 4-input positive NOR gate with strobe and expandable input
03	Dual 4-input positive NOR gate with strobe
04	Triple 3-input positive NOR gate

1.2.2 Device class. The device class is the product assurance level as defined in MIL-PRF-38535.

1.2.3 Case outlines. The case outlines are as designated in MIL-STD-1835 and as follows:

<u>Outline letter</u>	<u>Descriptive designator</u>	<u>Terminals</u>	<u>Package style</u>
A	GDFP5-F14 or CDFP6-F14	14	Flat pack
B	GDFP4-14	14	Flat pack
C	GDIP1-T14 or CDIP2-T14	14	Dual-in-line
D	GDFP1-F14 or CDFP2-F14	14	Flat pack
E	GDIP1-T16 or CDIP2-T16	16	Dual-in-line
F	GDFP2-F16 or CDFP3-F16	16	Flat-pack

Comments, suggestions, or questions on this document should be addressed to: Commander, Defense Supply Center Columbus, ATTN: DSCC-VAS, P. O. Box 3990, Columbus, OH 43218-3990, or emailed to bipolar@dsccl.dla.mil. Since contact information can change, you may want to verify the currency of this address information using the ASSIST Online database at <http://assist.daps.dla.mil>.

1.2.4 Absolute maximum ratings.

Supply voltage range	-0.5 V dc to +7.0 V dc
Input voltage range	-1.5 V dc at -12 mA to +5.5 V dc
Storage temperature range	-65°C to +150°C
Maximum power dissipation per gate, P_D	60 mW dc ^{1/}
Lead temperature (soldering 10 seconds)	300°C
Thermal resistance, junction-to-case (θ_{JC}).....	(See MIL-STD-1835)
Junction temperature (T_J) ^{2/}	175°C

1.2 Recommended operating conditions.

Supply voltage.....	4.5 V dc minimum to 5.5 V dc maximum
Minimum high level input voltage	2.0 V dc
Maximum low level input voltage	0.8 V dc
Normalized fanout (each output)	10 maximum
Case operating temperature range (T_C)	-55°C to 125°C

2.0 APPLICABLE DOCUMENT

2.1 General. The documents listed in this section are specified in sections 3, 4, or 5 of this specification. This section does not include documents cited in other sections of this specification or recommended for additional information or as examples. While every effort has been made to ensure the completeness of this list, document users are cautioned that they must meet all specified requirements of documents cited in sections 3, 4, or 5 of this specification, whether or not they are listed.

2.2 Government documents.

2.2.1 Specifications and standards. The following specifications and standards form a part of this specification to the extent specified herein. Unless otherwise specified, the issues of these documents are those cited in the solicitation or contract.

DEPARTMENT OF DEFENSE SPECIFICATIONS

MIL-PRF-38535 - Integrated Circuits (Microcircuits) Manufacturing, General Specification for.

DEPARTMENT OF DEFENSE STANDARDS

MIL-STD-883 - Test Method Standard for Microelectronics.
MIL-STD-1835 - Interface Standard Electronic Component Case Outlines

(Copies of these documents are available online at <http://assist.daps.dla.mil/quicksearch/> or <http://assist.daps.dla.mil> or from the Standardization Document Order Desk, 700 Robbins Avenue, Building 4D, Philadelphia, PA 19111-5094.)

2.3 Order of precedence. In the event of a conflict between the text of this specification and the references cited herein, the text of this document takes precedence. Nothing in this document, however, supersedes applicable laws and regulations unless a specific exemption has been obtained.

^{1/} Must withstand the added P_D due to short circuit condition (e.g. I_{OS}) at one output for 5 seconds duration.

^{2/} Maximum junction temperature should not be exceeded except in accordance with allowable short duration burn-in screening condition in accordance with MIL-PRF-38535.

3. REQUIREMENTS

3.1 Qualification. Microcircuits furnished under this specification shall be products that are manufactured by a manufacturer authorized by the qualifying activity for listing on the applicable qualified manufacturers list before contract award (see 4.3 and 6.4).

3.2 Item requirements. The individual item requirements shall be in accordance with MIL-PRF-38535 and as specified herein or as modified in the device manufacturer's Quality Management (QM) plan. The modification in the QM plan shall not affect the form, fit, or function as described herein.

3.3 Design, construction, and physical dimensions. The design, construction, and physical dimensions shall be as specified in MIL-PRF-38535 and herein.

3.3.1 Logic diagram and terminal connections. The logic diagram and terminal connections shall be as specified on figure 1.

3.3.2 Truth tables and logic equations. The truth tables and logic equations shall be as specified on figure 2.

3.3.3 Schematic circuit. The schematic circuit shall be maintained by the manufacturer and made available to the qualifying activity and the preparing activity upon request.

3.3.4 Case outlines. Case outlines shall be as specified in 1.2.3.

3.4 Lead material and finish. Lead material and finish shall be in accordance with MIL-PRF-38535 (see 6.6).

3.5 Electrical performance characteristics. The electrical performance characteristics are as specified in table 1 and apply over the full recommended case operating temperature range, unless otherwise specified.

3.6 Electrical test requirements. The electrical test requirements for each device class shall be the subgroups specified in table II. The electrical tests for each subgroup are described in table III.

3.7 Marking. Marking shall be in accordance with MIL-PRF-38535.

3.8 Microcircuit group assignment. The devices covered by this specification shall be in microcircuit group number 1 (see MIL-PRF-38535, appendix A).

4. VERIFICATION

4.1 Sampling and inspection. Sampling and inspection procedures shall be in accordance with MIL-PRF-38535 or as modified in the device manufacturer's Quality Management (QM) plan. The modification in the QM plan shall not effect the form, fit, or function as described herein.

4.2 Qualification inspection. Qualification inspection shall be in accordance with MIL-PRF-38535.

4.2 Screening. Screening shall be in accordance with MIL-PRF-38535 and shall be conducted on all devices prior to qualification and conformance inspection. The following additional criteria shall apply:

- a. The burn-in test duration, test condition, and test temperature, or approved alternatives shall be as specified in the device manufacturer's QM plan in accordance with MIL-PRF-38535. The burn-in test circuit shall be maintained under document control by the device manufacturer's Technology Review Board (TRB) in accordance with MIL-PRF-38535 and shall be made available to the acquiring or preparing activity upon request. The test circuit shall specify the inputs, outputs, biases, and power dissipation, as applicable, in accordance with the intent specified in test method 1015 of MIL-STD-883.
- b. Interim and final electrical test parameters shall be as specified in table II, except interim electrical parameters test prior to burn-in is optional at the discretion of the manufacturer.
- c. Additional screening for space level product shall be as specified in MIL-PRF-38535.

TABLE I. Electrical performance characteristics.

Test	Symbol	Conditions -55°C ≤ T _C ≤ +125°C unless otherwise specified	Device type	Limits		
				Min	Max	Unit
High-level output voltage	V _{OH}	V _{CC} = 4.5 V, V _{IN} = 0.8 V, I _{OH} = -800 μA	03, 04	2.4		V
		V _{CC} = 4.5 V, V _{IN} = 0.8 V, I _{OH} = -400 μA	01	2.4		V
		V _{CC} = 4.5 V, V _{IN} = 0.8 V mA, I _{OH} = -800 μA	02	2.4		V
		V _{CC} = 4.5 V, I _X = 0.15 mA, I _X = 0.15 mA, I _{OH} = -400 μA <u>1/</u>				
Low-level output voltage	V _{OL}	V _{CC} = 4.5 V, I _{OL} = 16 mA, V _{IN} = 2.0 V <u>2/</u>	01, 03 04		0.4	V
		V _{CC} = 4.5 V, V _{IN} = 2.0 V, I _{OL} = 16 mA <u>2/</u>	02		0.4	V
		V _{CC} = 4.5 V, I _X = 0.3 mA, R _X = 138 Ω, I _{OL} = 16 mA <u>3/</u>				
Expander current	I _X	V _{CC} = 5.0 V, I _{OL} = 16 mA, V _X = 0.4V, T _C = -55° C <u>4/</u>	02		3.5	mA
Base-emitter voltage	V _{BE}	V _{CC} = 5.0 V, I _X = 0.41 mA, I _{OL} = 16 mA, T _C = -55° C <u>5/</u>	02		1.1	V
High-level input current	I _{IH1}	V _{CC} = 5.5 V, Data input = 2.4 V	All		40	μA
		V _{CC} = 5.5 V, Strobe input = 2.4 V	02, 03		160	μA
High-level input current	I _{IH2}	V _{CC} = 5.5 V, Data input = 5.5 V	All		100	μA
		V _{CC} = 5.5 V, Strobe input = 5.5 V	02, 03		400	μA
Low-level input current	I _{IL1}	V _{CC} = 5.5 V, Data input = 0.4 V <u>6/</u>	01	-55	-1.6	mA
			02, 03, 04	-1.7	-1.6	mA
	I _{IL2}	V _{CC} = 5.5 V, Strobe input = 0.4 V <u>6/</u>	02, 03	-2.8	-6.4	mA
Short-circuit output current	I _{OS}	V _{CC} = 5.5 V, V _{IN} = 0 V <u>7/</u>	All	-20	-55	mA
High-level supply current per gate	I _{CCH}	V _{CC} = 5.5 V, V _{IN} = 0 V	01		4	mA
			02, 03		8	mA
			04		5.2	mA

See footnotes at end of table.

TABLE I. Electrical performance characteristics - Continued.

Test	Symbol	Conditions $-55^{\circ}\text{C} \leq T_C \leq +125^{\circ}\text{C}$ unless otherwise specified	Device type	Limits		
Low-level supply current per gate	I_{CCL}	$V_{\text{CC}} = 5.5 \text{ V}, V_{\text{IN}} = 5 \text{ V}$	01		6.5	mA
			02, 03		9.5	mA
			04		8.5	mA
Input clamp voltage	V_{IC}	$V_{\text{CC}} = 4.5 \text{ V}, I_{\text{IN}} = -12 \text{ mA},$ $T_C = 25^{\circ}\text{C}$	All		-1.5	V
Propagation delay time high-to-low level	t_{PHL}	$C_L = 50 \text{ pF}$ minimum, $R_L = 390 \Omega \pm 5 \text{ percent}$	All	3	24	ns
Propagation delay time low-to-high level	t_{PLH}	$C_L = 50 \text{ pF}$ minimum, $R_L = 390 \Omega \pm 5 \text{ percent}$	01, 03, 04	3	27	ns
			02	3	30	ns

1/ See test figure 7.2/ All unspecified inputs grounded.3/ See test figure 6.4/ See test figure 9.5/ See test figure 8.6/ All unspecified inputs at 5.5 V.7/ Not more than one output should be shorted at a time.

TABLE II. Electrical test requirements.

MIL-PRF-38535 Test requirement	Subgroups (see table III)	
	Class S Devices	Class B Devices
Interim electrical parameters	1	1
Final electrical test parameters	1*, 2, 3, 7, 9, 10, 11	1*, 2, 3, 7, 9
Group A test requirements	1, 2, 3, 7, 8, 9, 10, 11	1, 2, 3 7, 9
Group B electrical test parameters when using the method 5005 QCI option	1, 2, 3, 7, 8, 9, 10, 11	1, 2, 3 7, 9
Groups C end point electrical parameters	1, 2, 3, 7, 8, 9, 10, 11	1, 2, 3
Additional electrical subgroups for Group C periodic inspections	None	10, 11

*PDA applies to subgroup 1 (see 4.3c.).

4.3 Qualification inspection. Qualification inspection shall be in accordance with MIL-PRF-38535.

4.4 Technology Conformance Inspection (TCI). Technology conformance inspection shall be in accordance with MIL-PRF-38535 and herein for groups A, B, C, and D inspections (see 4.4.1 through 4.4.4).

4.4.1 Group A inspection. Group A inspection shall be in accordance with table III of MIL-PRF-38535 and as follows:

- a. Tests shall be as specified in table II herein.
- b. Subgroups 4, 5, and 6 shall be omitted.

4.4.2 Group B inspection. Group B inspection shall be in accordance with table II of MIL-PRF-38535.

4.4.3 Group C inspection. Group C inspection shall be in accordance with table IV of MIL-PRF-38535 and as follows:

- a. End point electrical parameters shall be as specified in table II herein.
- b. Subgroups 3 and 4 shall be added to the group C inspection requirements for class B devices and shall consist of the tests, conditions, and limits specified for subgroups 10 and 11 of group A.
- c. The steady-state life test duration, test condition, and test temperature, or approved alternatives shall be as specified in the device manufacturer's QM plan in accordance with MIL-PRF-38535. The burn-in test circuit shall be maintained under document control by the device manufacturer's Technology Review Board (TRB) in accordance with MIL-PRF-38535 and shall be made available to the acquiring or preparing activity upon request. The test circuit shall specify the inputs, outputs, biases, and power dissipation, as applicable, in accordance with the intent specified in test method 1005 of MIL-STD-883.

4.4.4 Group D inspection. Group D inspection shall be in accordance with table V of MIL-PRF-38535. End-point electrical parameters shall be as specified in table II herein.

4.5 Methods of inspection. Methods of inspection shall be as specified in the appropriate tables and as follows:

4.5.1 Voltage and current. All voltages given are referenced to the microcircuit ground terminal. Currents given are conventional current and positive when flowing into the referenced terminal.

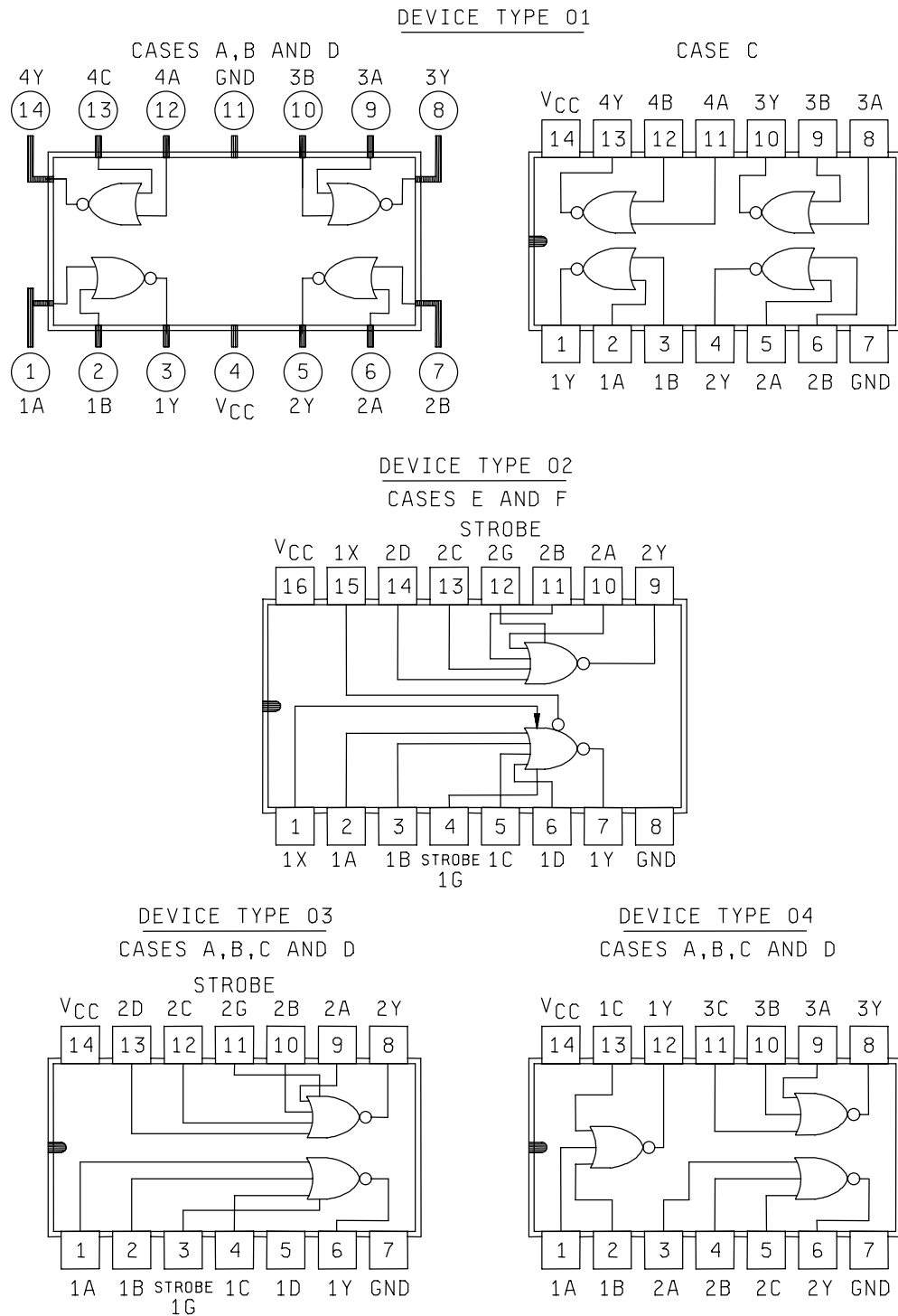


Figure 1. Logic diagram and terminal connections (top view).

Device type 01

Truth table each gate		
Input		Output
A	B	Y
H	X	L
X	H	L
L	L	H

X = Irrelevant

Positive logic: $Y = \overline{A + B}$

Device type 02

Truth table gate 1						
Input						Output
1A	1B	1C	1D	1X	1G	1Y
H	X	X	X	X	H	L
X	H	X	X	X	H	L
X	X	H	X	X	H	L
X	X	X	H	X	H	L
X	X	X	X	ON	X	L
L	L	L	L	OFF	X	H
X	X	X	X	OFF	L	H

X = Irrelevant

1X = Expander Input

Positive logic: $1Y = 1G(1A + 1B + 1C + 1D + 1X)$

Truth table gate 2					
Input					Output
2A	2B	2C	2D	2G	2Y
H	X	X	X	H	L
X	H	X	X	H	L
X	X	H	X	H	L
X	X	X	H	H	L
L	L	L	L	X	H
X	X	X	X	L	H

X = Irrelevant

Positive logic: $2Y = \overline{2G(2A + 2B + 2C + 2D)}$

Figure 2. Truth tables and logic equations.

Device type 03

Truth table each gate					
Input					Output
A	B	C	D	G	Y
H	X	X	X	H	L
X	H	X	X	H	L
X	X	H	X	H	L
X	X	X	H	H	L
L	L	L	L	X	H
X	X	X	X	L	H

X = Irrelevant

Positive logic: $Y = \overline{G(A + B + C + D)}$

Device type 04

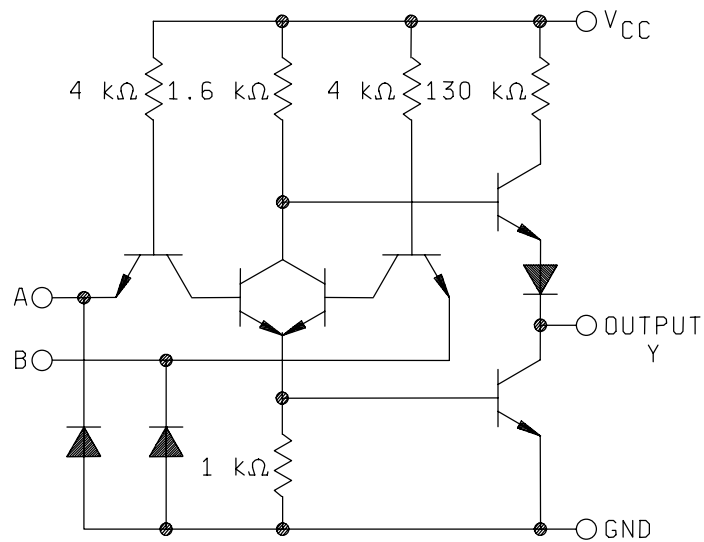
Truth table each gate			
Input			Output
A	B	C	Y
H	X	X	L
X	H	X	L
X	X	H	L
L	L	L	H

X = Irrelevant

Positive logic: $Y = \overline{A + B + C}$ Figure 2. Truth tables and logic equations – Continued.

DEVICE TYPE 01

CIRCUIT A
(EACH GATE)



NOTE: Component values shown are nominal.

DEVICE TYPE 01

CIRCUIT B
(EACH GATE)

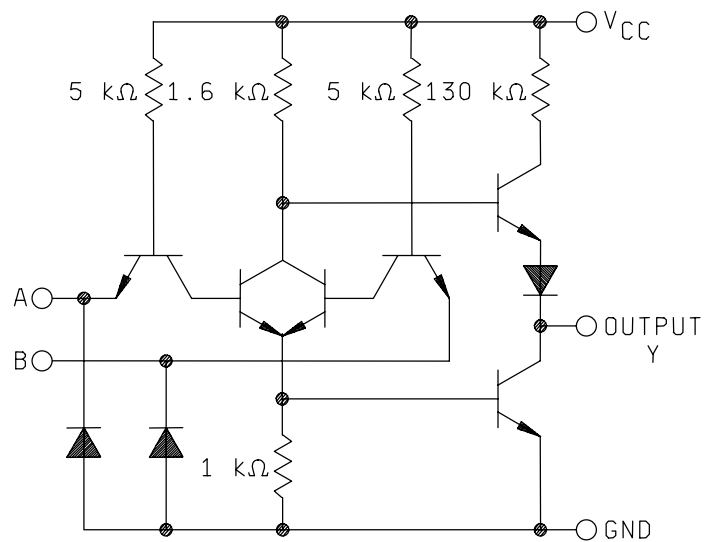


FIGURE 3. Schematic circuits.

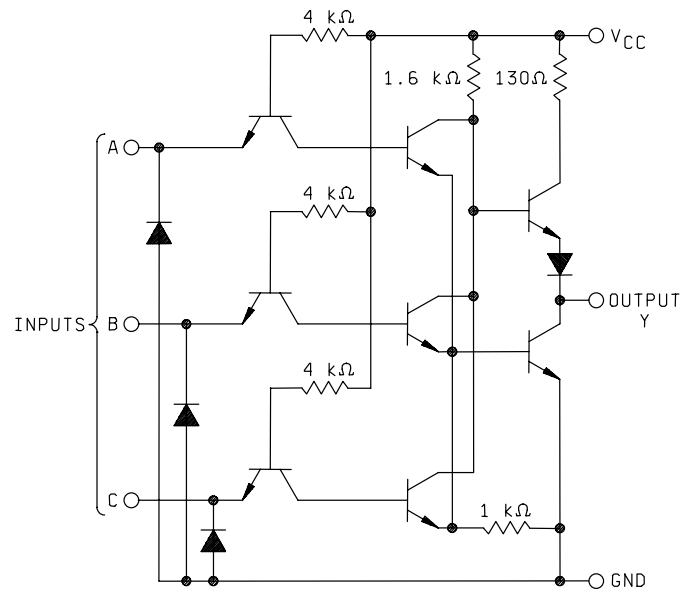


- FIGURE 3. Schematic circuits - Continued.

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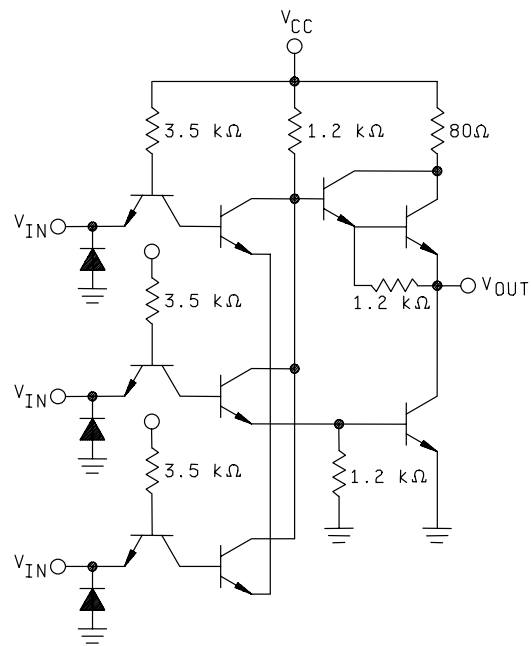
DEVICE TYPE 04

CIRCUIT A
(EACH GATE)



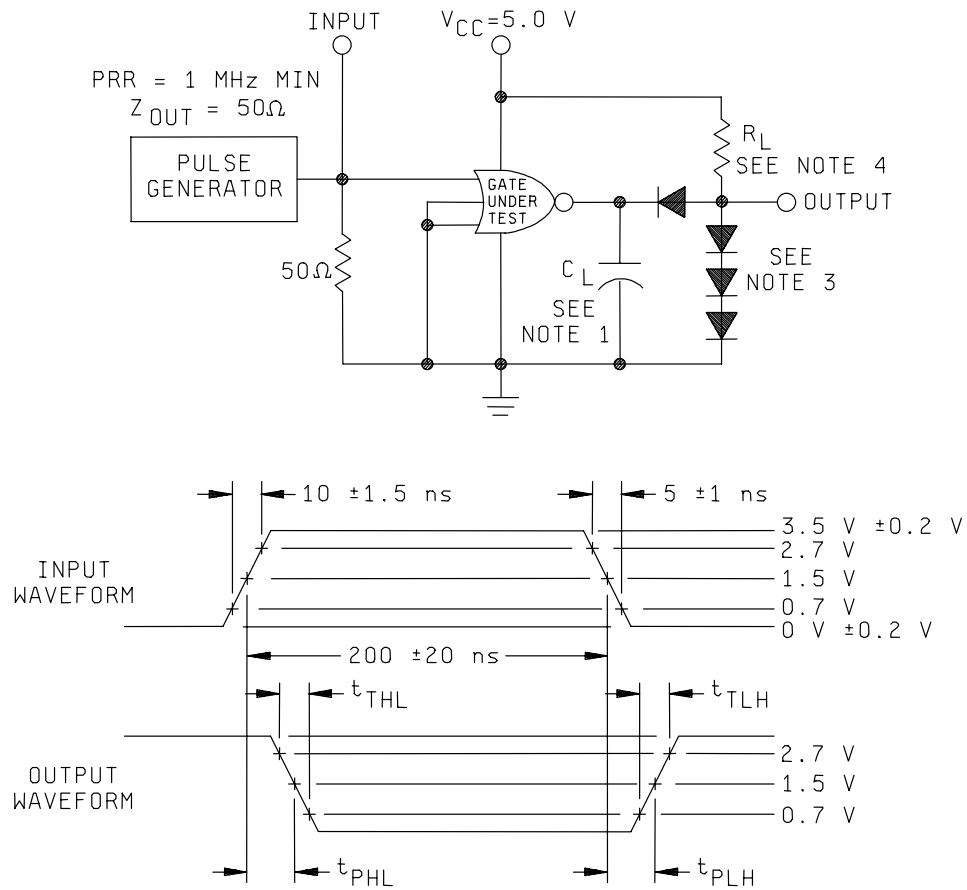
DEVICE TYPE 04

CIRCUIT B



NOTE: Component values shown are nominal.

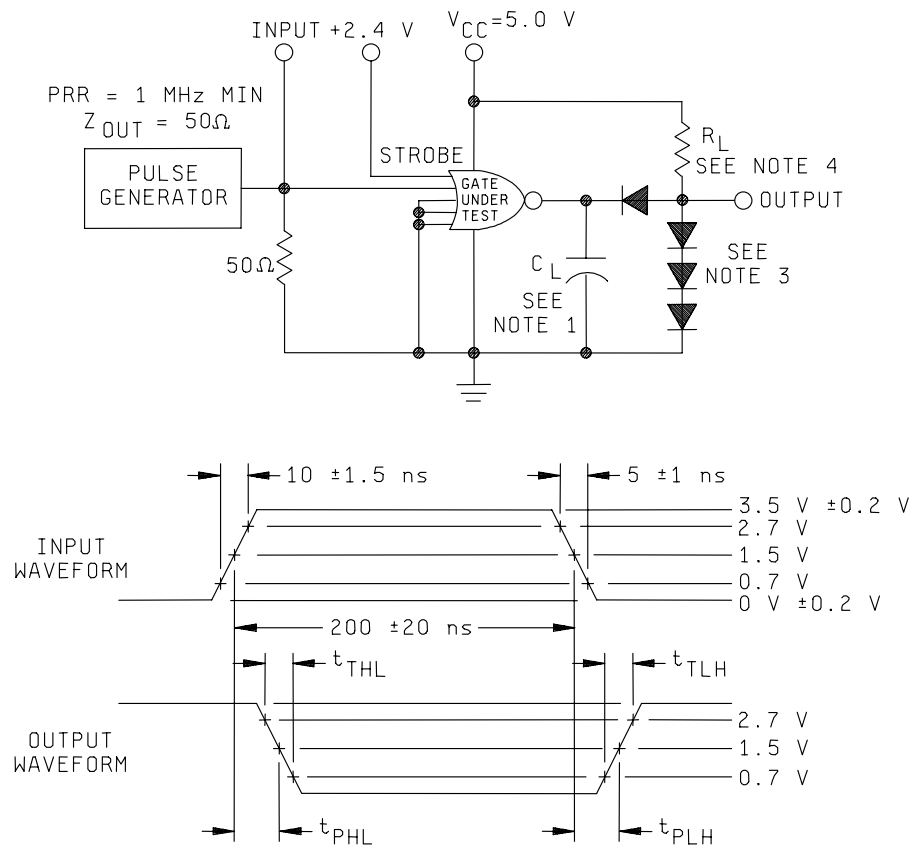
FIGURE 3. Schematic circuits - Continued.



NOTES:

1. $C_L = 50\text{ pF}$ minimum including scope probe, wiring, and stray capacitance, without package in test fixture.
2. Voltage measurements are to be made with respect to network ground terminal.
3. All diodes are 1N3064 or equivalent.
4. $R_L = 390\Omega \pm 5\%$.

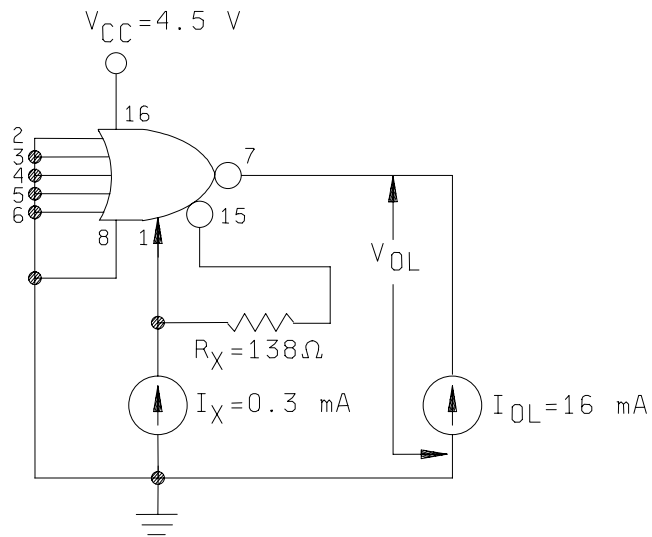
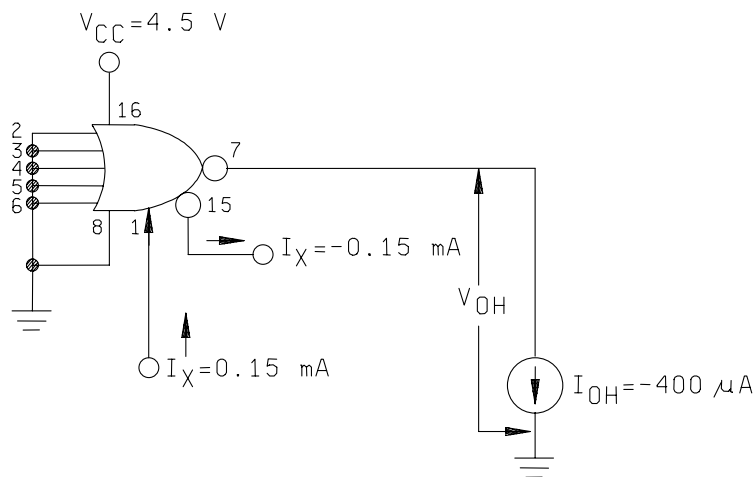
FIGURE 4. Switching time test circuit for device types 01 and 04.



NOTES:

1. $C_L = 50 \text{ pF}$ minimum including scope probe, wiring, and stray capacitance, without package in test fixture.
2. Voltage measurements are to be made with respect to network ground terminal.
3. All diodes are 1N3064 or equivalent.
4. $R_L = 390 \Omega \pm 5\%$.

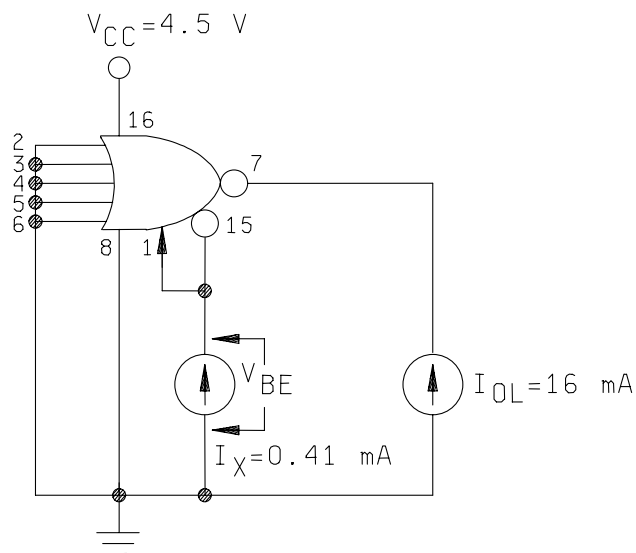
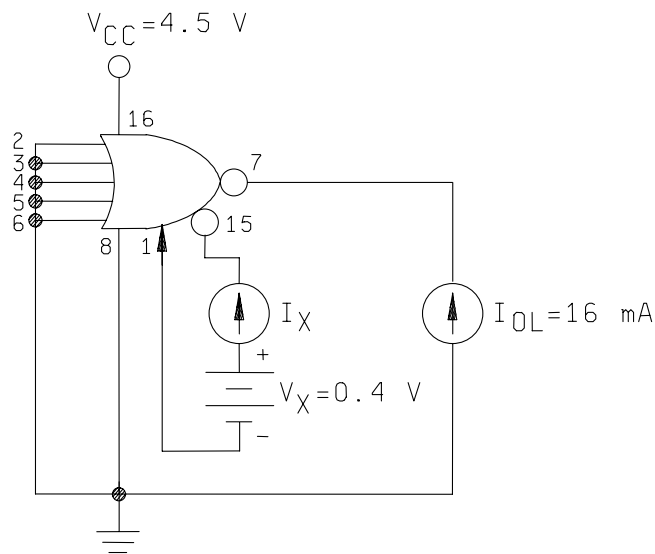
FIGURE 5. Switching time test circuit for device types 02 and 03.

FIGURE 6. Low level output voltage test circuit for device type 02.

NOTE:

At the manufacturer's option, the high level output voltage for the expanded inputs, may be verified by an alternate equivalent procedure. The procedure is to omit the $-400\ \mu\text{A}$ current source on pin 7 (Y) and to connect a $6\ \text{k}\Omega \pm 1\%$ resistor in parallel with a voltmeter between the output pin and ground. The V_{OH} minimum limit is met if the resultant voltage drop across the resistor is greater than 2.4 V.

FIGURE 7. High level output voltage test circuit for device type 02.

FIGURE 8. Base emitter voltage test circuit for device type 02.

NOTE:

At the manufacturer's option, the expander test current limit may be verified by the use of an alternate equivalent procedure. The V_X voltage source and the I_X meter may be replaced with a $110\Omega \pm 1\%$ resistor in parallel with a voltmeter between pins 1 and 15 (X to X). When the applicable conditions are applied, the resultant voltage drop across the resistor is measured. The I_X limit of 3.5 mA is met if the resultant voltage does not exceed 0.4 V.

FIGURE 9. Expander current test circuit for device type 02.

TABLE III. Group A inspection for device type 01.
Terminal conditions (pins not designated may be H \geq 2.0 V or L \leq 0.8 V or open).

Subgroup	Symbol	MIL-STD-883 method	Cases A,B,D	1	2	3	4	5	6	7	8	9	10	11	12	13	14	Meas. terminal	Test limits			
			Case C	2	3	1	14	4	5	6	10	8	9	7	11	12	13		Min	Max	Unit	
			Test No.	1A	1B	1Y	V _{CC}	2Y	2A	2B	3Y	3A	3B	GND	4A	4B	4Y					
1 T _C = 25°C	V _{OL}	3007	1	2.0 V	GND	16 mA	4.5 V		GND	GND		GND	GND	GND	GND	GND		1Y		0.4	V	
	"	"	2	GND	2.0 V	16 mA	"		GND	"		"	"	"	"	"		1Y		"	"	
	"	"	3	"	GND		"	16 mA	2.0 V	"		"	"	"	"	"		2Y		"	"	
	"	"	4	"	"		"	16 mA	GND	2.0 V		"	"	"	"	"		2Y		"	"	
	"	"	5	"	"		"	"	GND	2.0 V	16 mA	"	"	"	"	"		3Y		"	"	
	"	"	6	"	"		"	"	"	GND	"	2.0 V	"	"	"	"		3Y		"	"	
	"	"	7	"	"		"	"	"	"	"	GND	"	2.0 V	"	16 mA	4Y		"	"		
	"	"	8	"	"		"	"	"	"	"	GND	"	GND	2.0 V	16 mA	4Y		"	"		
	"	V _{OH}	3006	9	0.8 V	0.8 V	-400 μA	"	-400 μA	5.5 V	5.5 V		5.5 V	5.5 V	"	5.5 V	5.5 V		1Y	2.4		"
	"	"	10	5.5 V	5.5 V		"	"	0.8 V	0.8 V	-400 μA	5.5 V	5.5 V	"	"	"		2Y		"	"	
	"	"	11	"	"		"	"	5.5 V	5.5 V	"	0.8 V	0.8 V	"	"	"		3Y		"	"	
	"	"	12	"	"		"	"	5.5 V	5.5 V		5.5 V	5.5 V	"	0.8 V	0.8 V	-400 μA	4Y		"	"	
	"	I _{OS}	3011	13	GND	GND	GND	5.5 V		GND	GND				"				1Y	-20	-55	mA
	"	"	"	14				"	GND			GND			"				2Y		"	"
	"	"	"	15				"				GND	GND		"				3Y		"	"
	"	"	"	16				"						"	GND	GND	GND	4Y		"	"	
	"	I _{IH1}	3010	17	2.4 V	GND		"		GND	GND		GND	GND	"	GND	GND		1A		40	μA
	"	"	"	18	GND	2.4 V		"		GND	"		"	"	"	"	"		1B		"	"
	"	"	"	19	"	GND		"		2.4 V	"		"	"	"	"	"		2A		"	"
	"	"	"	20	"	"		"		GND	2.4 V		"	"	"	"	"		2B		"	"
	"	"	"	21	"	"		"		"	GND		2.4 V	"	"	"	"		3A		"	"
	"	"	"	22	"	"		"		"	"		GND	2.4 V	"	"	"		3B		"	"
	"	"	"	23	"	"		"		"	"		"	GND	"	2.4 V	"		4A		"	"
	"	"	"	24	"	"		"		"	"		"	"	"	GND	2.4 V		4B		"	"
	"	I _{IH2}	3010	25	5.5 V	"		"		"	"		"	"	"	"	GND		1A		100	"
	"	"	"	26	GND	5.5 V		"		"	"		"	"	"	"			1B		100	"

TABLE III. Group A inspection for device type 01. - Continued
Terminal conditions (pins not designated may be H \geq 2.0 V or L \leq 0.8 V or open).

Subgroup	Symbol	MIL-STD-883 method	Cases A,B,D	1	2	3	4	5	6	7	8	9	10	11	12	13	14	Meas. terminal	Test limits			
			Case C	2	3	1	14	4	5	6	10	8	9	7	11	12	13		Min	Max	Unit	
			Test No.	1A	1B	1Y	V _{CC}	2Y	2A	2B	3Y	3A	3B	GND	4A	4B	4Y					
1 T _C = 25°C	I _{IH2}	3010	27	GND	GND		5.5 V		5.5 V	GND		GND	GND	GND	GND	GND		2A		100	μA	
	"	"	28	"	"		"		GND	5.5 V		GND	"	"	"	"		2B		"	"	
	"	"	29	"	"		"		"	GND		5.5 V	"	"	"	"		3A		"	"	
	"	"	30	"	"		"		"	"		GND	5.5 V	"	"	"		3B		"	"	
	"	"	31	"	"		"		"	"		"	GND	5.5 V	"	"		4A		"	"	
"	"	"	32	"	"		"		"	"		"	GND	GND	5.5 V	5.5 V		4B		"	"	
"	I _{IL}	3009	33 CKT A	0.4 V	5.5 V		"		5.5 V	5.5 V		5.5 V	5.5 V	"	5.5 V	5.5 V		1A	-7	-1.6	mA	
	"	"	33 CKT B	0.4 V	5.5 V		"		"	"		"	"	"	"	"		1A	-.55	-1.45	"	
	"	"	34 CKT A	5.5.v	0.4 V		"		"	"		"	"	"	"	"		1B	-7	-1.6	"	
	"	"	34 CKT B		0.4 V		"		"	"		"	"	"	"	"		1B	-.55	-1.45	"	
	"	"	35 CKT A	"	5.5 V		"		0.4 V	"		"	"	"	"	"		2A	-7	-1.6	"	
	"	"	35 CKT B	"	"		"		0.4 V	"		"	"	"	"	"		2A	-.55	-1.45	"	
	"	"	36 CKT A	"	"		"		5.5 V	0.4 V		"	"	"	"	"		2B	-7	-1.6	"	
	"	"	36 CKT B	"	"		"		"	0.4 V		"	"	"	"	"		2B	-.55	-1.45	"	
	"	"	37 CKT A	"	"		"		"	5.5 V		0.4 V	"	"	"	"		3A	-7	-1.6	"	
	"	"	37 CKT B	"	"		"		"	"		0.4 V	"	"	"	"		3A	-.55	-1.45	"	
	"	"	38 CKT A	"	"		"		"	"		5.5 V	0.4 V	"	"	"		3B	-7	-1.6	"	
	"	"	38 CKT B	"	"		"		"	"		"	0.4 V	"	"	"		3B	-.55	-1.45	"	
	"	"	39 CKT A	"	"		"		"	"		"	5.5 V	"	0.4 V	"		4A	-7	-1.6	"	
	"	"	39 CKT B	"	"		"		"	"		"	"	"	0.4 V	"		4A	-.55	-1.45	"	
	"	"	40 CKT A	"	"		"		"	"		"	"	"	5.5 V	0.4 V		4B	-7	-1.6	"	
	"	"	40 CKT B	"	"		"		"	"		"	"	"	5.5 V	0.4 V		4B	-.55	-1.45	"	
	"	I _{CCH}	3005	41	GND	GND		"		GND	GND		GND	GND	"	GND	GND		V _{CC}		16	mA
	"	I _{CCL}	3005	42	5.0 V	5.0 V		"		5.0 V	5.0 V		5.0 V	5.0 V	"	5.0 V	5.0 V		V _{CC}		26	mA
	"	V _{IC}		43	-12 mA	-12 mA		4.5 V		-12 mA	-12 mA		-12 mA	-12 mA	"				1A		-1.5	V
		"		44			"		"						1B		"	"				
"			45		"			"				2A				"	"					
"			46		"			"				2B				"	"					
"			47		"		"		3A		"	"										
"			48		"		"		3B		"	"										
"			49		"		"		4A		"	"										
"	"		50		"		"		"		"		"	-12 mA	-12 mA		4B		"	"		
2	Same tests, terminal conditions and limits as for subgroup 1, except T _C = 125° C and V _{IC} tests are omitted.																					
3	Same tests, terminal conditions and limits as for subgroup 1, except T _C = -55° C and V _{IC} tests are omitted.																					

TABLE III. Group A inspection for device type 01.
Terminal conditions (pins not designated may be $H \geq 2.0$ V or $L \leq 0.8$ V or open).

Subgroup	Symbol	MIL-STD-883 method	Cases A,B,D	1	2	3	4	5	6	7	8	9	10	11	12	13	14	Meas. terminal	Test limits			
			Case C	2	3	1	14	4	5	6	10	8	9	7	11	12	13		Min	Max	Unit	
			Test No.	1A	1B	1Y	V _{CC}	2Y	2A	2B	3Y	3A	3B	GND	4A	4B	4Y					
9 T _C = 25°C " " " "	τ _{PHL}	3003 (Fig. 4)	51 52 53 54	IN	GND	OUT	5.0 V " " "	OUT	IN	GND		OUT	IN	GND	GND " " "			OUT	1A to 1Y 2A to 2Y 3A to 3Y 4A to 4Y	3 " " "	20 " " "	ns " " "
	τ _{PLH}	"	55 56 57 58	IN	GND	OUT	" " " "	OUT	IN	GND		OUT	IN	GND	" " " "			OUT	1A to 1Y 2A to 2Y 3A to 3Y 4A to 4Y	3 " " "	25 " " "	" " " "
	τ _{PHL}	"	59 60 61 62	IN	GND	OUT	" " " "		IN	GND		OUT	IN	GND	" " " "			OUT	1A to 1Y 2A to 2Y 3A to 3Y 4A to 4Y	3 " " "	24 " " "	" " " "
	τ _{PLH}	"	63 64 65 66	IN	GND	OUT	" " " "	OUT	IN	GND		OUT	IN	GND	" " " "	IN	GND	OUT	1A to 1Y 2A to 2Y 3A to 3Y 4A to 4Y	3 " " "	27 " " "	" " " "
	Same tests, terminal conditions and limits as for subgroup 10, except T _C = -55°C.																					

TABLE III. Group A inspection for device type 02.
Terminal conditions (pins not designated may be H \geq 2.0 V or L \leq 0.8 V or open).

Subgroup	Symbol	MIL-STD-883 method	Cases E, F	1	2	3	4	5	6	7	8	9	10	11	12	13	14	15	16	Meas. terminal	Test limits		
			Test No.	1X	1A	1B	1G	1C	1D	1Y	GND	2Y	2A	2B	2G	2C	2D	1X	V _{CC}		Min	Max	Unit
1 T _C = 25°C	V _{OL}	3007	1		2.0 V	GND	2.0 V	GND	GND	16 mA	GND		GND	GND	GND	GND	GND		4.5 V	1Y		0.4	V
	"	"	2		GND	2.0 V	"	GND	"	"	"		"	"	"	"	"		"	1Y		"	"
	"	"	3		"	GND	"	2.0 V	"	"	"		"	"	"	"	"		"	1Y		"	"
	"	"	4		"	"	"	GND	2.0 V	"	"		"	"	"	"	"		"	1Y		"	"
	"	"	5	1/	"	"	GND	"	GND	"	"		"	"	"	"	"	1/	"	1Y		"	"
	"	"	6		"	"	"	"	"		"	16 mA	2.0 V	"	2.0 V	"	"		"	2Y		"	"
	"	"	7		"	"	"	"	"		"	"	GND	2.0 V	"	"	"		"	2Y		"	"
	"	"	8		"	"	"	"	"		"	"	"	GND	"	2.0 V	"		"	2Y		"	"
	"	"	9		"	"	"	"	"		"	"	"	GND	"	GND	2.0 V		"	2Y		"	"
"	V _{OH}	3006	10		0.8 V	0.8 V	5.5 V	0.8 V	0.8 V	-800 μ A	"		5.5 V	5.5 V	5.5 V	5.5 V	5.5 V		"	1Y	2.4		"
	"	"	11		5.5 V	5.5 V	0.8 V	5.5 V	5.5 V	-800 μ A	"		"	"	"	"	"		"	1Y		"	"
	"	"	12	2/	GND	GND	GND	GND	GND	-400 μ A	"		"	"	"	"	"	2/	"	1Y		"	"
	"	"	13		5.5 V	5.5 V	5.5 V	5.5 V	5.5 V	"	"	-800 μ A	0.8 V	0.8 V	"	0.8 V	0.8 V		"	2Y		"	"
	"	"	14		5.5 V	5.5 V	5.5 V	5.5 V	5.5 V	"	"	-800 μ A	5.5 V	5.5 V	0.8 V	5.5 V	5.5 V		"	2Y		"	"
	I _{OS}	3011	15		GND	GND	GND	GND	GND	GND	"								5.5 V	1Y	-20	-55	mA
	I _{OS}	3011	16								"	GND	GND	GND	GND	GND	GND		"	2Y	-20	-55	mA
	I _{IH1}	3010	17		2.4 V	GND	GND	GND	GND		"								"	1A		40	μ A
	"	"	18		GND	2.4 V	"	"	"		"								"	1B		40	"
"	"	"	19		"	GND	2.4 V	"	"		"								"	1G		160	"
	"	"	20		"	"	GND	2.4 V	"		"								"	1C		40	"
	"	"	21		"	"	GND	GND	2.4 V		"								"	1D		"	"
	"	"	22								"		2.4 V	GND	GND	GND	GND		"	2A		"	"
	"	"	23								"		"	2.4 V	"	"	"		"	2B		"	"
	"	"	24								"		"	"	2.4 V	"	"		"	2G		160	"
	"	"	25								"		"	"	GND	2.4 V	"		"	2C		40	"
	"	"	26								"		"	"	GND	GND	2.4 V		"	2D		40	"
"	I _{IH2}	3010	27		5.5 V	GND	GND	GND	GND		"								"	1A		100	"
	"	"	28		GND	5.5 V	"	"	"		"								"	1B		100	"
	"	"	29		"	GND	5.5 V	"	"		"								"	1G		400	"
	"	"	30		"	"	GND	5.5 V	"		"								"	1C		100	"
	"	"	31		"	"	GND	GND	5.5 V		"								"	1D		"	"
	"	"	32								"		5.5 V	GND	GND	GND	GND		"	2A		"	"
	"	"	33								"		"	5.5 V	GND	"	"		"	2B		"	"
	"	"	34								"		"	"	5.5 V	"	"		"	2G		400	"
	"	"	35								"		"	"	GND	5.5 V	"		"	2C		100	"
	"	"	36								"		"	"	GND	GND	5.5 V		"	2D		100	"

See footnotes at end of device type 02.

TABLE III. Group A inspection for device type 02. - Continued
Terminal conditions (pins not designated may be H \geq 2.0 V or L \leq 0.8 V or open).

Subgroup	Symbol	MIL-STD-883 method	Cases E, F	1	2	3	4	5	6	7	8	9	10	11	12	13	14	15	16	Meas. terminal	Test limits		
			Test No.	1X	1A	1B	1G	1C	1D	1Y	GND	2Y	2A	2B	2G	2C	2D	1X	V _{CC}		Min	Max	Unit
1 T _C = 25°C	I _{IL1}	3009	37		0.4 V	5.5 V	5.5 V	5.5 V	5.5 V		GND								5.5 V	1A	-.7	-1.6	mA
	"	"	38		5.5 V	0.4 V	"	5.5 V	"		"								"	1B	"	"	"
	"	"	39		"	5.5 V	"	0.4 V	"		"								"	1C	"	"	"
	"	"	40		"	5.5 V	"	5.5 V	0.4 V		"								"	1D	"	"	"
	"	"	41								"		0.4 V	5.5 V	5.5 V	5.5 V	5.5 V		"	2A	"	"	"
	"	"	42								"		5.5 V	0.4 V	"	5.5 V	"		"	2B	"	"	"
	"	"	43								"		"	"	"	0.4 V	"		"	2C	"	"	"
	"	"	44								"		"	"	"	5.5 V	0.4 V		"	2D	"	"	"
	I _{IL2}	3009	45		5.5 V	5.5 V	0.4 V	5.5 V	5.5 V		"								"	1G	-2.8	-6.4	mA
	I _{IL2}	3009	46								"		5.5 V	5.5 V	0.4 V	5.5 V	5.5 V		"	2G	-2.8	-6.4	mA
	I _{CCL}	3005	47		5.0 V	5.0 V	5.0 V	5.0 V	5.0 V		"		5.0 V	5.0 V	5.0 V	5.0 V	5.0 V		"	V _{CC}		19	mA
	I _{CCH}	3005	48		GND	GND	GND	GND	GND		"		GND	GND	GND	GND	GND		"	V _{CC}		16	mA
	V _{IC}		49		-12 mA						"								4.5 V	1A		-1.5	V
	"		50			-12 mA					"								"	1B		"	"
	"		51				-12 mA				"								"	1G		"	"
	"		52					-12 mA			"								"	1C		"	"
	"		53						-12 mA		"								"	1D		"	"
	"		54								"		-12 mA						"	2A		"	"
	"		55								"			-12 mA					"	2B		"	"
	"		56								"				-12 mA				"	2G		"	"
	"		57								"					-12 mA			"	2C		"	"
	"		58								"						-12 mA		"	2D		"	"
2	Same tests, terminal conditions and limits as for subgroup 1, except T _C = 125° C and V _{IC} tests are omitted.																						
3 T _C = -55°C	I _X		59	3/	GND	GND	GND	GND	GND	16 mA	GND							3/	4.5 V	1 X		3.5	mA
	V _{BE}		60	4/	GND	GND	GND	GND	GND	16 mA	GND							4/	4.5 V	1 X		1.1	V
Remainder of subgroup consists of the same tests, terminal conditions and limits as for subgroup 1, except T _C = -55°C and V _{IC} tests are omitted.																							
9 T _C = 25°C	t _{PHL}	3003 Fig 5	61		IN	GND	2.4 V	GND	GND	OUT	GND		IN	GND	2.4 V	GND	GND		5.0 V	1A to 1Y	3	20	ns
			62								"	OUT							"	2A to 2Y	3	20	ns
	t _{PLH}		63		IN	GND	2.4 V	GND	GND	OUT	"		IN	GND	2.4 V	GND	GND		"	1A to 1Y	3	27	ns
			64								"	OUT							"	2A to 2Y	3	27	ns
10 T _C = 125°C	t _{PHL}		65		IN	GND	2.4 V	GND	GND	OUT	"		IN	GND	2.4 V	GND	GND		"	1A to 1Y	3	24	ns
			66								"	OUT							"	2A to 2Y	3	24	ns

See footnotes at end of device type 02.

TABLE III. Group A inspection for device type 02. - Continued
Terminal conditions (pins not designated may be H \geq 2.0 V or L \leq 0.8 V or open).

Subgroup	Symbol	MIL-STD-883 method	Cases E, F	1	2	3	4	5	6	7	8	9	10	11	12	13	14	15	16	Meas. terminal	Test limits		
			Test No.	1X	1A	1B	1G	1C	1D	1Y	GND	2Y	2A	2B	2G	2C	2D	1X	V _{CC}		Min	Max	Unit
10	t _{PLH}	3003	67		IN	GND	2.4 V	GND	GND	OUT	GND								5.0 V	1A to 1Y	3	30	ns
T _C = 125°C		Fig 5	68								GND	OUT	IN	GND	2.4 V	GND	GND		5.0 V	2A to 2Y	3	30	ns
11	Same tests, terminal conditions and limits as for subgroup 10, except T _C = -55°C.																						

- 1/ See test figure 6.
2/ See test figure 7.
3/ See test figure 8.
4/ See test figure 9.

TABLE III. Group A inspection for device type 03.
Terminal conditions (pins not designated may be H \geq 2.0 V or L \leq 0.8 V or open).

Subgroup	Symbol	MIL-STD-883 method	Cases A,B,D	1	2	3	4	5	6	7	8	9	10	11	12	13	14	Meas. terminal	Test limits		
			Case C	1	2	3	4	5	6	7	8	9	10	11	12	13	14		Min	Max	Unit
			Test No.	1A	1B	1G	1C	1D	1Y	GND	2Y	2A	2B	2G	2C	2D	V _{CC}				
1 T _C = 25°C	V _{OL}	3007	1	2.0 V	GND	2.0 V	GND	GND	16 mA	GND		GND	GND	GND	GND	GND	4.5 V	1Y		0.4	V
	"	"	2	GND	2.0 V	"	GND	"	"	"		"	"	"	"	"	"	1Y		"	"
	"	"	3		GND	"	2.0 V	"	"	"		"	"	"	"	"	"	1Y		"	"
	"	"	4	"	"	"	GND	2.0 V	"	"		"	"	"	"	"	"	1Y		"	"
	"	"	5	"	"	GND	"	GND		"	16 mA	2.0 V	"	2.0 V	"	"	"	2Y		"	"
	"	"	6	"	"	"	"	"		"		GND	2.0 V	"	"	"	"	2Y		"	"
	"	"	7	"	"	"	"	"		"	"	"	GND	"	2.0 V	"	"	2Y		"	"
	"	"	8	"	"	"	"	"		"	"	"	GND	"	GND	2.0 V	"	2Y		"	"
	V _{OH}	3006	9	0.8 V	0.8 V	5.5 V	0.8 V	0.8 V	-800 μ A	"		5.5 V	5.5 V	5.5 V	5.5 V	5.5 V	"	1Y	2.4		"
	"	"	10	5.5 V	5.5 V	0.8 V	5.5 V	5.5 V	-800 μ A	"		5.5 V	5.5 V	5.5 V	5.5 V	5.5 V	"	1Y	"		"
	"	"	11	"	"	5.5 V	"	"		"	-800 μ A	0.8 V	0.8 V	5.5 V	0.8 V	0.8 V	"	2Y	"		"
	"	"	12	"	"	5.5 V	"	"		"	-800 μ A	5.5 V	5.5 V	0.8 V	5.5 V	5.5 V	"	2Y	"		"
	I _{OS}	3011	13	GND	GND	GND	GND	GND	GND	"							5.5 V	1Y	-20	-55	mA
	I _{OS}	3011	14							"	GND	GND	GND	GND	GND	GND	"	2Y	-20	-55	mA
	I _{IH1}	3010	15	2.4 V	GND	GND	GND	GND		"							"	1A		40	μ A
	"	"	16	GND	2.4 V	GND	"	"		"							"	1B		40	"
	"	"	17	"	GND	2.4 V	"	"		"							"	1G		160	"
	"	"	18	"	"	GND	2.4 V	"		"							"	1C		40	"
	"	"	19	"	"	GND	GND	2.4 V		"							"	1D		"	"
	"	"	20							"		2.4 V	GND	GND	GND	GND	"	2A		"	"
	"	"	21							"		GND	2.4 V	GND	"	"	"	2B		"	"
	"	"	22							"		GND	GND	2.4 V	"	"	"	2G		160	"
	"	"	23							"		"	GND	GND	2.4 V	"	"	2C		40	"
	"	"	24							"		"	GND	GND	GND	2.4 V	"	2D		40	"
	I _{IH2}	3010	25	5.5 V	GND	GND	GND	GND		"							"	1A		100	"
	I _{IH2}	3010	26	GND	5.5 V	GND	GND	GND		"							"	1B		100	"

TABLE III. Group A inspection for device type 03. - Continued
Terminal conditions (pins not designated may be H \geq 2.0 V or L \leq 0.8 V or open).

Subgroup	Symbol	MIL-STD-883 method	Cases A,B,D	1	2	3	4	5	6	7	8	9	10	11	12	13	14	Meas. terminal	Test limits		
			Case C	1	2	3	4	5	6	7	8	9	10	11	12	13	14		Min	Max	Unit
			Test No.	1A	1B	1G	1C	1D	1Y	GND	2Y	2A	2B	2G	2C	2D	V _{CC}				
1 T _C = 25°C	I _{IH2}	3010	27	GND	GND	5.5 V	GND	GND		GND							5.5 V	1G		400	μA
	"	"	28	"	"	GND	5.5 V	GND		"							"	1C		100	"
	"	"	29	"	"	GND	GND	5.5 V		"							"	1D		"	"
	"	"	30							"		5.5 V	GND	GND	GND	GND	"	2A		"	"
	"	"	31							"		GND	5.5 V	GND	"	"	"	2B		"	"
	"	"	32							"		"	GND	5.5 V	"	"	"	2G		400	"
	"	"	33							"		"	"	GND	5.5 V	"	"	2C		100	"
	"	"	34							"		"	"	GND	GND	5.5 V	"	2D		100	"
"	I _{IL1}	3009	35	0.4 V	5.5 V	5.5 V	5.5 V	5.5 V		"							"	1A	-7	-1.6	mA
	"	"	36	5.5 V	0.4 V	"	5.5 V	"		"							"	1B	-7	-1.6	"
	"	"	37	"	5.5 V	"	0.4 V	"		"							"	1C	-7	-1.6	"
	"	"	38	"	5.5 V	"	5.5 V	0.4 V		"							"	1D	-7	-1.6	"
	"	"	39							"		0.4 V	5.5 V	5.5 V	5.5 V	5.5 V	"	2A	-7	-1.6	"
	"	"	40							"		5.5 V	0.4 V	"	5.5 V	"	"	2B	-7	-1.6	"
	"	"	41							"		"	5.5 V	"	0.4 V	"	"	2C	-7	-1.6	"
	"	"	42							"		"	5.5 V	"	5.5 V	0.4 V	"	2D	-7	-1.6	"
"	I _{IL2}	3009	43	5.5 V	5.5 V	0.4 V	5.5 V	5.5 V		"							"	1G	-2.8	-6.4	mA
	I _{IL2}	3009	44							"		5.5 V	5.5 V	0.4 V	5.5 V	5.5 V	"	2G	-2.8	-6.4	"
"	I _{CC} L	3005	45	5.0 V	5.0 V	5.0 V	5.0 V	5.0 V		"		5.0 V	5.0 V	5.0 V	5.0 V	5.0 V	"	V _{CC}		19	"
"	I _{CC} H	3005	46	GND	GND	GND	GND	GND		"		GND	GND	GND	GND	GND	"	V _{CC}		16	"
"	V _{IC}		47	-12 mA						"							4.5 V	1A		-1.5	V
	"		48		-12 mA					"							"	1B		"	"
	"		49			-12 mA				"							"	1G		"	"
	"		50				-12 mA			"							"	1C		"	"
	"		51					-12 mA		"							"	1D		"	"
	"		52							"		-12 mA					"	2A		"	"

TABLE III. Group A inspection for device type 03. - Continued
Terminal conditions (pins not designated may be $H \geq 2.0$ V or $L \leq 0.8$ V or open).

Subgroup	Symbol	MIL-STD-883 method	Cases A,B,D	1	2	3	4	5	6	7	8	9	10	11	12	13	14	Meas. terminal	Test limits		
			Case C	1	2	3	4	5	6	7	8	9	10	11	12	13	14		Min	Max	Unit
			Test No.	1A	1B	1G	1C	1D	1Y	GND	2Y	2A	2B	2G	2C	2D	V _{CC}				
1 T _C = 25°C " "	V _{IC}		53							GND			-12 mA				4.5 V	2B		-1.5	V
	"		54							"				-12 mA			"	2G		"	"
	"		55							"					-12 mA		"	2C		"	"
	"		56							"						-12 mA	"	2D		"	"
2	Same tests, terminal conditions and limits as for subgroup 1, except T _C = 125°C and V _{IC} tests are omitted.																				
3	Same tests, terminal conditions and limits as for subgroup 1, except T _C = -55°C and V _{IC} tests are omitted.																				
9 T _C = 25°C " "	t _{PHL}	3003	57	IN	GND	2.4 V	GND	GND	OUT	GND							5.0 V	1A to 1Y	3	20	ns
	t _{PHL}	(Fig. 5)	58							"	OUT	IN	GND	2.4 V	GND	GND	"	2A to 2Y	3	20	"
	t _{PLH}	"	59	IN	GND	2.4 V	GND	GND	OUT	"							"	1A to 1Y	3	25	"
	t _{PLH}	"	60							"	OUT	IN	GND	2.4 V	GND	GND	"	2A to 2Y	3	25	"
10 T _C = 125°C " "	t _{PHL}	"	61	IN	GND	2.4 V	GND	GND	OUT	"							"	1A to 1Y	3	24	"
	t _{PHL}	"	62							"	OUT	IN	GND	2.4 V	GND	GND	"	2A to 2Y	3	24	"
	t _{PLH}	"	63	IN	GND	2.4 V	GND	GND	OUT	"							"	1A to 1Y	3	27	"
	t _{PLH}	"	64							"	OUT	IN	GND	2.4 V	GND	GND	"	2A to 2Y	3	27	"
11	Same tests, terminal conditions and limits as for subgroup 10, except T _C = -55°C.																				

TABLE III. Group A inspection for device type 04.
Terminal conditions (pins not designated may be $H \geq 2.0$ V or $L \leq 0.8$ V or open).

Subgroup	Symbol	MIL-STD-883 method	Cases A,B,D	1	2	3	4	5	6	7	8	9	10	11	12	13	14	Meas. terminal	Test limits		
			Case C	1	2	3	4	5	6	7	8	9	10	11	12	13	14		Min	Max	Unit
			Test No.	1A	1B	2A	2B	2C	2Y	GND	3Y	3A	3B	3C	1Y	1C	V _{CC}				
1 T _C = 25°C	V _{OL}	3007	1	2.0 V	GND	GND	GND	GND		GND		GND	GND	GND	16 mA	GND	4.5 V	1Y		.4	V
	"	"	2	GND	2.0 V	"	"	"		"		"	"	"	"	GND	"	1Y		"	"
	"	"	3	"	GND	"	"	"		"		"	"	"	"	2.0 V	"	1Y		"	"
	"	"	4	"	"	2.0 V	"	"	16 mA	"		"	"	"	"	GND	"	2Y		"	"
	"	"	5	"	"	GND	2.0 V	"	"	"		"	"	"	"	"	"	2Y		"	"
	"	"	6	"	"	"	GND	2.0 V	"	"		"	"	"	"	"	"	2Y		"	"
	"	"	7	"	"	"	"	GND		"	16 mA	2.0 V	"	"	"	"	"	3Y		"	"
	"	"	8	"	"	"	"	"		"	"	GND	2.0 V	"	"	"	"	3Y		"	"
	"	"	9	"	"	"	"	"		"	"	GND	GND	2.0 V	"	"	"	3Y		"	"
	V _{OH}	3006	10	0.8 V	0.8 V	5.5 V	5.5 V	5.5 V		"		5.5 V	5.5 V	5.5 V	-800 μA	0.8 V	"	1Y	2.4		"
	"	"	11	5.5 V	5.5 V	0.8 V	0.8 V	0.8 V	-800 μA	"		5.5 V	5.5 V	5.5 V	"	5.5 V	"	2Y	"		"
	"	"	12	5.5 V	5.5 V	5.5 V	5.5 V	5.5 V		"	-800 μA	0.8 V	0.8 V	0.8 V	"	5.5 V	"	3Y	"		"
	I _{OS}	3011	13	GND	GND					"					GND	GND	5.5 V	1Y	-20	-55	mA
	"	"	14							"							"	2Y	"		"
	"	"	15			GND	GND	GND	GND	"	GND	GND	GND	GND			"	3Y	"		"
	I _{IH1}	3010	16	2.4 V	GND	GND	GND	GND		"		GND	"	"		GND	"	1A		40	μA
	"	"	17	GND	2.4 V	GND	"	"		"		"	"	"		"	"	1B		"	"
	"	"	18	"	GND	2.4 V	"	"		"		"	"	"		"	"	2A		"	"
	"	"	19	"	"	GND	2.4 V	"		"		"	"	"		"	"	2B		"	"
	"	"	20	"	"	"	GND	2.4 V		"		"	"	"		"	"	2C		"	"
	"	"	21	"	"	"	"	GND		"		2.4 V	"	"		"	"	3A		"	"
	"	"	22	"	"	"	"	"		"		GND	2.4 V	"		"	"	3B		"	"
	"	"	23	"	"	"	"	"		"		"	GND	2.4 V		"	"	3C		"	"
	"	"	24	"	"	"	"	"		"		"	"	GND		2.4 V	"	1C		"	"
	I _{IH2}	3010	25	5.5 V	GND	GND	GND	GND		"		GND	"	GND		GND	"	1A		100	"
	I _{IH2}	3010	26	GND	5.5 V	GND	GND	GND		"		GND	"	GND		GND	"	1B		100	"

TABLE III. Group A inspection for device type 04. - Continued
Terminal conditions (pins not designated may be H \geq 2.0 V or L \leq 0.8 V or open).

Subgroup	Symbol	MIL-STD-883 method	Cases A,B,D	1	2	3	4	5	6	7	8	9	10	11	12	13	14	Meas. terminal	Test limits		
			Case C	1	2	3	4	5	6	7	8	9	10	11	12	13	14		Min	Max	Unit
			Test No.	1A	1B	2A	2B	2C	2Y	GND	3Y	3A	3B	3C	1Y	1C	V _{CC}				
1 T _C = 25°C	I _{IH2}	3010	27	GND	GND	5.5 V	GND	GND		GND		GND	GND	GND		GND	5.5 V	2A		100	μA
	"	"	28	"	"	GND	5.5 V	GND		"		"	"	"		"	"	2B		"	"
	"	"	29	"	"	"	GND	5.5 V		"		"	"	"		"	"	2C		"	"
	"	"	30	"	"	"	"	GND		"		5.5 V	"	"		"	"	3A		"	"
	"	"	31	"	"	"	"	"		"		GND	5.5 V	"		"	"	3B		"	"
	"	"	32	"	"	"	"	"		"		"	GND	5.5 V		"	"	3C		"	"
	"	"	33	"	"	"	"	"		"		"	GND	GND		5.5 V	"	1C		"	"
	I _{IL}	3009	34	0.4 V	5.5 V	5.5 V	5.5 V	5.5 V		"		5.5 V	5.5 V	5.5 V		"	"	1A	-7	-1.6	mA
	"	"	35	5.5 V	0.4 V	"	"	"		"		"	"	"		"	"	1B	"	"	"
	"	"	36	"	5.5 V	0.4 V	"	"		"		"	"	"		"	"	2A	"	"	"
	"	"	37	"	"	5.5 V	0.4 V	"		"		"	"	"		"	"	2B	"	"	"
	"	"	38	"	"	"	5.5 V	0.4 V		"		"	"	"		"	"	2C	"	"	"
	"	"	39	"	"	"	"	5.5 V		"		0.4 V	"	"		"	"	3A	"	"	"
	"	"	40	"	"	"	"	"		"		5.5 V	0.4 V	"		"	"	3B	"	"	"
	"	"	41	"	"	"	"	"		"		"	5.5 V	0.4 V		"	"	3C	"	"	"
	"	"	42	"	"	"	"	"		"		"	5.5 V	5.5 V		0.4 V	"	1C	"	"	"
	I _{CCH}	3005	43	GND	GND	GND	GND	GND		"		GND	GND	GND		GND	"	V _{CC}		15.6	
	I _{CCL}	3005	44	5.0 V	5.0 V	5.0 V	5.0 V	5.0 V		"		5.0 V	5.0 V	5.0 V		5.0 V	"	V _{CC}		25.5	
	V _{IC}		45	-12 mA						"							4.5 V	1A		-1.5	V
	"		46		-12 mA					"							"	1B		"	"
	"		47			-12 mA				"							"	2A		"	"
	"		48				-12 mA			"							"	2B		"	"
	"		49					-12 mA		"							"	2C		"	"
	"		50							"		-12 mA					"	3A		"	"
	"		51							"			-12 mA				"	3B		"	"
	"		52							"				-12 mA			"	3C		"	"

TABLE III. Group A inspection for device type 04. - Continued
Terminal conditions (pins not designated may be H \geq 2.0 V or L \leq 0.8 V or open).

Subgroup	Symbol	MIL-STD-883 method	Cases A,B,D	1	2	3	4	5	6	7	8	9	10	11	12	13	14	Meas. terminal	Test limits		
			Case C	1	2	3	4	5	6	7	8	9	10	11	12	13	14		Min	Max	Unit
			Test No.	1A	1B	2A	2B	2C	2Y	GND	3Y	3A	3B	3C	1Y	1C	V _{CC}				
1 T _C = 25°C	V _{IC}		53							GND						-12 mA	4.5 V	1C		-1.5	V
2	Same tests, terminal conditions and limits as for subgroup 1, except T _C = 125°C and V _{IC} tests are omitted.																				
3	Same tests, terminal conditions and limits as for subgroup 1, except T _C = -55°C and V _{IC} tests are omitted.																				
9	t _{PHL}	3003 (Fig. 4)	54	IN	GND					GND					OUT	GND	5.0 V	1A to 1Y	3	20	ns
"	"	"	55			IN	GND	GND	OUT	"							"	2A to 2Y	"	"	"
"	"	"	56							"	OUT	IN	GND	GND			"	3A to 3Y	"	"	"
"	t _{PLH}	"	57	IN	GND					"					OUT	GND	"	1A to 1Y	3	25	"
"	"	"	58			IN	GND	GND	OUT	"							"	2A to 2Y	"	"	"
"	"	"	59							"	OUT	IN	GND	GND			"	3A to 3Y	"	"	"
10 T _C = 125°C	t _{PHL}	"	60	IN	GND					"					OUT	GND	"	1A to 1Y	3	24	"
"	"	"	61			IN	GND	GND	OUT	"							"	2A to 2Y	"	"	"
"	"	"	62							"	OUT	IN	GND	GND			"	3A to 3Y	"	"	"
"	t _{PLH}	"	63	IN	GND					"					OUT	GND	"	1A to 1Y	3	27	"
"	"	"	64			IN	GND	GND	OUT	"							"	2A to 2Y	"	"	"
"	"	"	65							"	OUT	IN	GND	GND			"	3A to 3Y	"	"	"
11	Same tests, terminal conditions and limits as for subgroup 10, except T _C = -55°C.																				

5. PACKAGING

5.1 Packaging requirements. For acquisition purposes, the packaging requirements shall be as specified in the contract or order (see 6.2). When actual packaging of materiel is to be performed by DoD or in-house contractor personnel, these personnel need to contact the responsible packaging activity to ascertain packaging requirements. Packaging requirements are maintained by the Inventory Control Point's packaging activity within the Military Service or Defense Agency, or within the military service's system command. Packaging data retrieval is available from the managing Military Department's or Defense Agency's automated packaging files, CD-ROM products, or by contacting the responsible packaging activity.

6. NOTES

6.1 Intended use. Microcircuits conforming to this specification are intended for original equipment design applications and logistic support of existing equipment.

6.2 Acquisition requirements. Acquisition documents should specify the following:

- a. Title, number, and date of the specification.
- b. PIN and compliance identifier, if applicable (see 1.2).
- c. Requirements for delivery of one copy of the conformance inspection data pertinent to the device inspection lot to be supplied with each shipment by the device manufacturer, if applicable.
- d. Requirement for certificate of compliance, if applicable.
- e. Requirements for notification of change of product or process to acquiring activity in addition to notification to the qualifying activity, if applicable.
- f. Requirements for failure analysis (including required test condition of method 5003), corrective action and reporting of results, if applicable.
- g. Requirements for product assurance options.
- h. Requirements for carriers, special lead lengths or lead forming, if applicable. These requirements shall not affect the part number. Unless otherwise specified, these requirements will not apply to direct purchase by or direct shipment to the Government.
- i. Requirements for "JAN" marking.
- j. Packaging requirements (see 5.1).

6.3 Superseding information. The requirements of MIL-M-38510 have been superseded to take advantage of the available Qualified Manufacturer Listing (QML) system provided by MIL-PRF-38535. Previous references to MIL-M-38510 in this document have been replaced by appropriate references to MIL-PRF-38535. All technical requirements now consist of this specification and MIL-PRF-38535. The MIL-M-38510 specification sheet number and PIN have been retained to avoid adversely impacting existing government logistics systems and contractor's parts lists.

6.4 Qualification. With respect to products requiring qualification, awards will be made only for products which are, at the time of award of contract, qualified for inclusion in Qualified Manufacturers List QML-38535 whether or not such products have actually been so listed by that date. The attention of the contractors is called to these requirements, and manufacturers are urged to arrange to have the products that they propose to offer to the Federal Government tested for qualification in order that they may be eligible to be awarded contracts or purchase orders for the products covered by this specification. Information pertaining to qualification of products may be obtained from DSCC-VQ, 3990 E. Broad Street, Columbus, Ohio 43123-1199.

6.5 Abbreviations, symbols and definitions. The abbreviations, symbols, and definitions used herein are defined in MIL-PRF-38535 and MIL-HDBK-1331, and as follows:

GND	Electrical ground (common terminal)
V _{IN}	Voltage level at an input terminal
V _{IC}	Input clamp voltage
I _{IN}	Current-flowing into an input terminal

6.6 Logistic support. Lead materials and finishes (see 3.3) are interchangeable. Unless otherwise specified, microcircuits acquired for Government logistic support will be acquired to device class B (see 1.2.2), lead material and finish A (see 3.4). Longer lead lengths and lead forming shall not affect the part number.

6.7 Substitutability. The cross-reference information below is presented for the convenience of users. Microcircuits covered by this specification will functionally replace the listed generic-industry type. Generic-industry microcircuit types may not have equivalent operational performance characteristics across military temperature ranges or reliability factors equivalent to MIL-M-35810 device types and may have slight physical variations in relation to case size. The presence of this information should not be deemed as permitting substitution of generic-industry types for MIL-M-38510 types or as a waiver of any of the provisions of MIL-PRF-38535.

<u>Device type</u>	<u>Commercial type</u>
01	5402
02	5423
03	5425
04	5427

6.8 Supersession information. MIL-M-0038510/4B was issued as an "in lieu of" document for MIL-M-38510/4A. This revision, MIL-M-38510/4D, supersedes MIL-M-0038510/4B(USAF) and MIL-M-38510/C.

6.9 Changes from previous issue. Marginal notations are not used in this revision to identify changes with respect to the previous issue due to the extensiveness of the changes.

Custodians:
 Army - CR
 Navy - EC
 Air Force - 11
 DLA - CC

Preparing activity:
 DLA - CC
 (Project 5962-2075)

Review activities:
 Army - MI, SM
 Navy - AS, CG, MC, SH, TD
 Air Force - 03, 19, 99

NOTE: The activities listed above were interested in this document as of the date of this document. Since organizations and responsibilities can change, you should verify the currency of the information above using the ASSIST Online database at <http://assist.daps.dla.mil>.